

Features

- AEC-Q101 Qualified
- Split Gate Trench MOSFET Technology
- Low $R_{DS(on)}$ & FOM
- Excellent Stability and Uniformity
- Extremely Low Switching Loss
- Epoxy Meets UL 94 V-0 Flammability Rating
- Halogen Free. "Green" Device
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)
- Moisture Sensitivity Level 1

Maximum Ratings

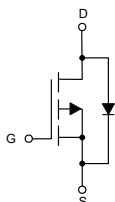
- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 50°C/W Junction to Ambient
- Thermal Resistance: 1.7°C/W Junction to Case

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V_{DS}	-100	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current	I_D	$T_C=25^\circ\text{C}$	-18 A
		$T_C=100^\circ\text{C}$	-12 A
Pulsed Drain Current ⁽¹⁾	I_{DM}	-72	A
Avalanche Energy ⁽²⁾	E_{AS}	36	mJ
Total Power Dissipation	P_D	72	W

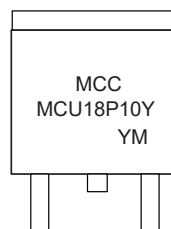
Note:

1. Pulse Test: Pulse Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 2\%$.
2. $T_J=25^\circ\text{C}$, $V_{DD}=-50\text{V}$, $V_G=-10\text{V}$, $L=0.5\text{mH}$, $R_g=25\Omega$.

Internal Structure and Marking Code



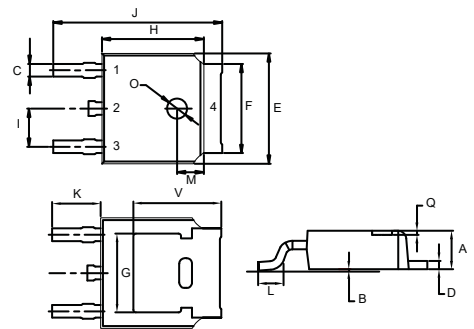
- 1.GATE
- 2.DRAIN
- 3.SOURCE
- 4.DRAIN



Y is the year
M is the month

P-CHANNEL MOSFET

DPAK



DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	0.087	0.094	2.20	2.40	
B	0.000	0.005	0.00	0.13	
C	0.026	0.034	0.66	0.86	
D	0.018	0.023	0.46	0.58	
E	0.256	0.264	6.50	6.70	
F	0.201	0.215	5.10	5.46	
G	0.190		4.83		TYP.
H	0.236	0.244	6.00	6.20	
I	0.086	0.094	2.18	2.39	
J	0.386	0.409	9.80	10.40	
K	0.114		2.90		TYP.
L	0.055	0.067	1.40	1.70	
M	0.063		1.60		TYP.
O	0.043	0.051	1.10	1.30	
Q	0.000	0.012	0.00	0.30	
V	0.211		5.35		TYP.

Electrical Characteristics @ 25°C (Unless Otherwise Specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS}=0V, I_D=-250\mu A$	-100			V
Gate-Source Leakage Current	I_{GSS}	$V_{DS}=0V, V_{GS}=\pm 20V$			± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=-100V, V_{GS}=0V$			-1	μA
		$V_{DS}=-100V, V_{GS}=0V, T_J=150^\circ C$			-100	μA
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=-250\mu A$	-1	-1.8	-2.5	V
Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=-10V, I_D=-10A$		83	110	m Ω
		$V_{GS}=-4.5V, I_D=-5A$		93	120	m Ω
Diode Characteristics						
Continuous Body Diode Current	I_S				-18	A
Diode Forward Voltage	V_{SD}	$V_{GS}=0V, I_S=-10A$			-1.3	V
Reverse Recovery Time	t_{rr}	$I_S=-5A, di/dt=100A/\mu s$		70		ns
Reverse Recovery Charge	Q_{rr}			140		nC
Dynamic Characteristics						
Input Capacitance	C_{iss}	$V_{DS}=-50V, V_{GS}=0V, f=1MHz$		1051		pF
Output Capacitance	C_{oss}			119		
Reverse Transfer Capacitance	C_{rss}			25		
Total Gate Charge	Q_g	$V_{DS}=-50V, V_{GS}=-10V, I_D=-5A$		20.1		nC
Gate-Source Charge	Q_{gs}			3.9		
Gate-Drain Charge	Q_{gd}			4.3		
Turn-On Delay Time	$t_{d(on)}$	$V_{GS}=-10V, V_{DD}=-50V, R_L=2.5\Omega$ $R_{GEN}=6\Omega$		10		ns
Turn-On Rise Time	t_r			30		
Turn-Off Delay Time	$t_{d(off)}$			77		
Turn-Off Fall Time	t_f			81		

Curve Characteristics

Fig. 1 - Typical Output Characteristics

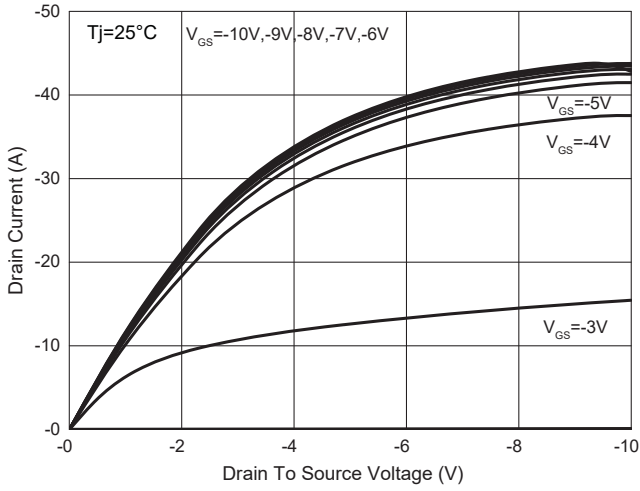


Fig. 2 - Transfer Characteristics

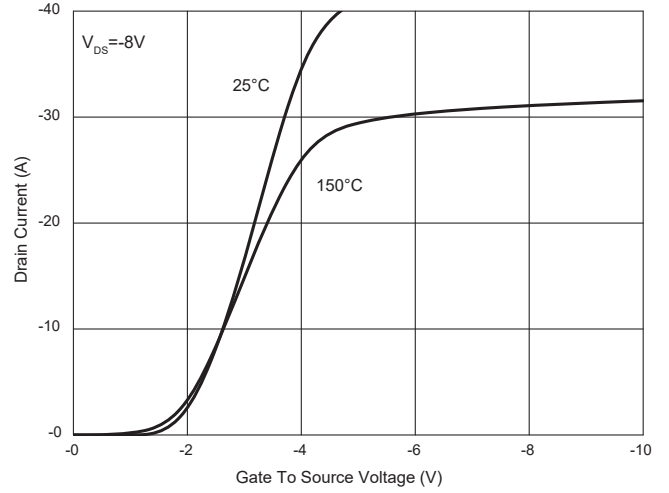


Fig. 3 - $R_{DS(ON)} - V_{GS}$

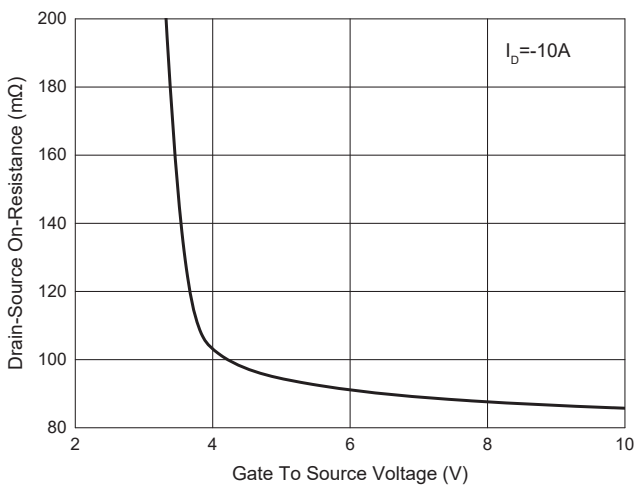


Fig. 4 - Normalized On Resistance Characteristics

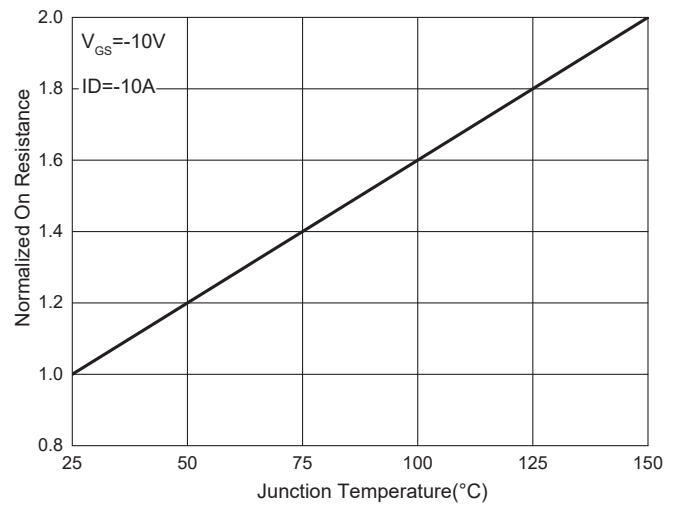


Fig. 5 - Capacitance Characteristics

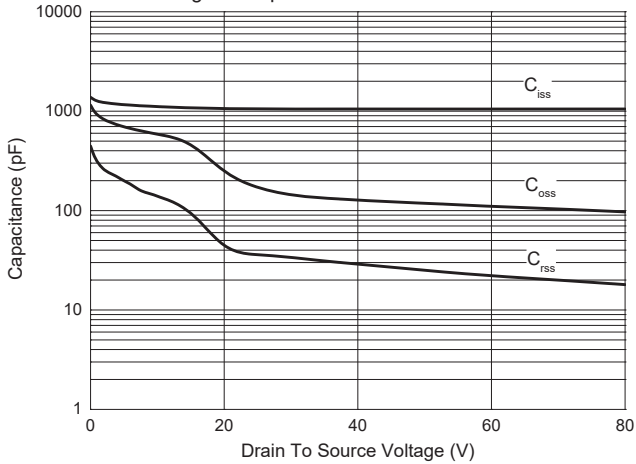
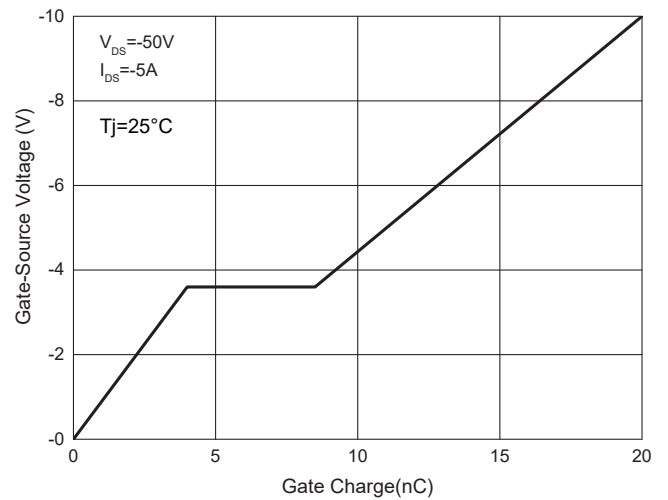


Fig. 6 - Gate Charge



Curve Characteristics

Fig. 7 - $I_S - V_{SD}$

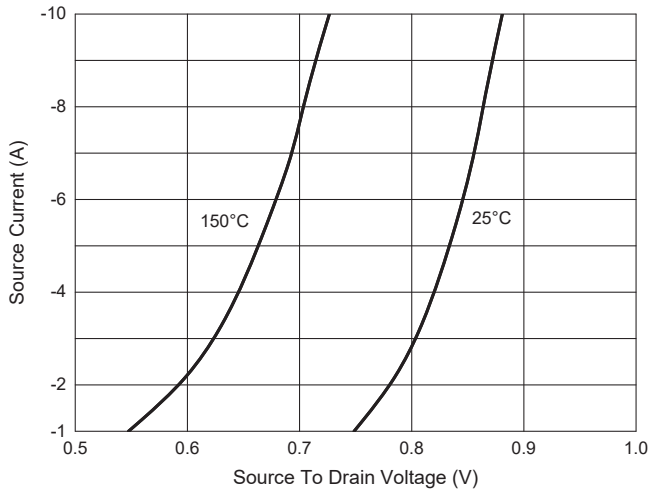


Fig. 8 - $R_{DS(ON)} - I_D$

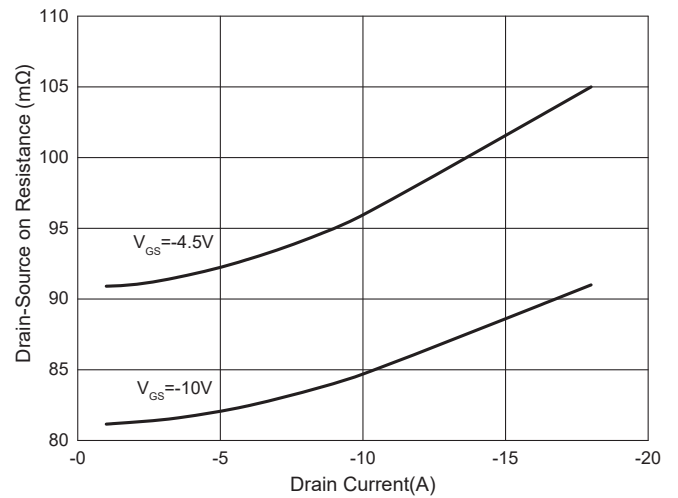


Fig. 9 - Safe Operation Area

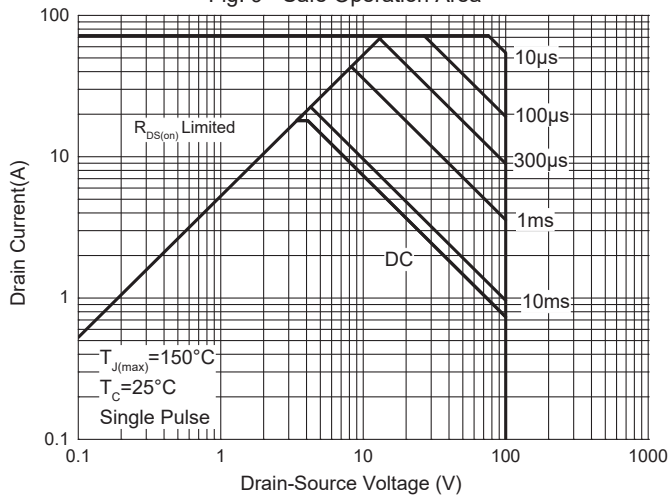
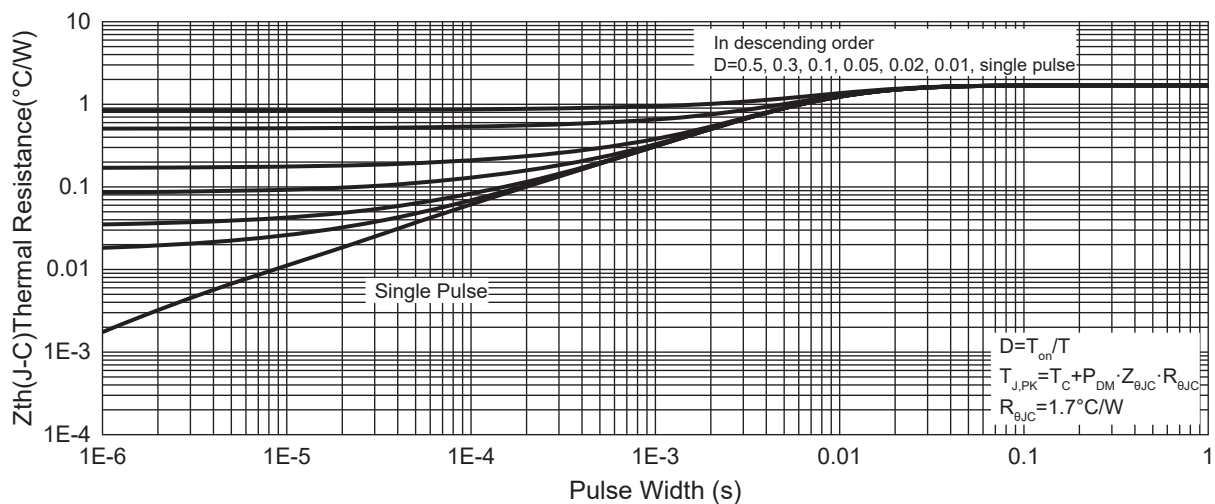


Fig. 10 - Maximum Transient Thermal Impedance



Ordering Information

Device	Packing
Part Number-TP	Tape&Reel: 2.5Kpcs/Reel

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